## Strictly Confidential: (For Internal and Restricted use only) Senior Secondary School Term II Examination, 2022 Marking Scheme – PHYSICS (SUBJECT CODE — 042) (PAPER CODE — 55/2/1)

## General Instructions: -

- 1. You are aware that evaluation is the most important process in the actual and correct assessment of the candidates. A small mistake in evaluation may lead to serious problems which may affect the future of the candidates, education system and teaching profession. To avoid mistakes, it is requested that before starting evaluation, you must read and understand the spot evaluation guidelines carefully.
- 2. "Evaluation policy is a confidential policy as it is related to the confidentiality of the examinations conducted, Evaluation done and several other aspects. Its' leakage to public in any manner could lead to derailment of the examination system and affect the life and future of millions of candidates. Sharing this policy/document to anyone, publishing in any magazine and printing in News Paper/Website etc may invite action under IPC."
- 3. Evaluation is to be done as per instructions provided in the Marking Scheme. It should not be done according to one's own interpretation or any other consideration. Marking Scheme should be strictly adhered to and religiously followed. However, while evaluating, answers which are based on latest information or knowledge and/or are innovative, they may be assessed for their correctness otherwise and marks be awarded to them. In class-X, while evaluating two competency based questions, please try to understand given answer and even if reply is not from marking scheme but correct competency is enumerated by the candidate, marks should be awarded.
- 4. The Head-Examiner must go through the first five answer books evaluated by each evaluator on the first day, to ensure that evaluation has been carried out as per the instructions given in the Marking Scheme. The remaining answer books meant for evaluation shall be given only after ensuring that there is no significant variation in the marking of individual evaluators.
- 5. Evaluators will mark( $\sqrt{}$ ) wherever answer is correct. For wrong answer 'X' be marked. Evaluators will not put right kind of mark while evaluating which gives an impression that answer is correct and no marks are awarded. This is most common mistake which evaluators are committing.
- 6. If a question has parts, please award marks on the right-hand side for each part. Marks awarded for different parts of the question should then be totalled up and written in the left-hand margin and encircled. This may be followed strictly.
- 7. If a question does not have any parts, marks must be awarded in the left-hand margin and encircled. This may also be followed strictly.
- 8. If a student has attempted an extra question, answer of the question deserving more marks should be retained and the other answer scored out.
- 9. No marks to be deducted for the cumulative effect of an error. It should be penalized only once.

- 10. A full scale of marks \_35\_(example 0-40 marks as given in Question Paper) has to be used. Please do not hesitate to award full marks if the answer deserves it.
- 11. Every examiner has to necessarily do evaluation work for full working hours i.e. 8 hours every day and evaluate 30 answer books per day in main subjects and 35 answer books per day in other subjects (Details are given in Spot Guidelines). This is in view of the reduced syllabus and number of questions in question paper.
- 12. Ensure that you do not make the following common types of errors committed by the Examiner in the past:-
  - Leaving answer or part thereof unassessed in an answer book.
  - Giving more marks for an answer than assigned to it.
  - Wrong totalling of marks awarded on a reply.
  - Wrong transfer of marks from the inside pages of the answer book to the title page.
  - Wrong question wise totalling on the title page.
  - Wrong totalling of marks of the two columns on the title page.
  - Wrong grand total.
  - Marks in words and figures not tallying.
  - Wrong transfer of marks from the answer book to online award list.
  - Answers marked as correct, but marks not awarded. (Ensure that the right tick mark is correctly and clearly indicated. It should merely be a line. Same is with the X for incorrect answer.)
  - Half or a part of answer marked correct and the rest as wrong, but no marks awarded.
- 13. While evaluating the answer books if the answer is found to be totally incorrect, it should be marked as cross (X) and awarded zero (0)Marks.
- 14. Any unassessed portion, non-carrying over of marks to the title page, or totalling error detected by the candidate shall damage the prestige of all the personnel engaged in the evaluation work as also of the Board. Hence, in order to uphold the prestige of all concerned, it is again reiterated that the instructions be followed meticulously and judiciously.
- 15. The Examiners should acquaint themselves with the guidelines given in the Guidelines for spot Evaluation before starting the actual evaluation.
- 16. Every Examiner shall also ensure that all the answers are evaluated, marks carried over to the title page, correctly totalled and written in figures and words.
- 17. The Board permits candidates to obtain photocopy of the Answer Book on request in an RTI application and also separately as a part of the re-evaluation process on payment of the processing charges.

## MARKING SCHEME

Senior Secondary School Examination TERM-II, 2022

## PHYSICS (Subject Code — 042)

[ Paper Code — 55/2/1 ]

Q. No.	EXPECTED ANSWER / VALUE POINTS	Marks	Total Marks
	SECTION—A		
1.	Explanation of Formation of Depletion region 2		
	When p-type semiconductor is chipped with n-type semiconductor, e <sup>-</sup> from the n-side diffuse towards p-side and holes from p-side diffuse towards n-side leaving behind a layer of immobile +ve ions on n-side and immobile -ve ions on p-side leading to formation of depletion layer.	2	
	( Note : Award 1 mark, if a student draws a diagram showing depletion region)		2
2.	a)  Definition of impact parameter & distance of closest approach Values ½ + ½  Value of Impact parameter for (I) & (II) ½ + ½		
	i. <b>Impact Parameter</b> : It is the perpendicular distance of the initial velocity vector of the approaching $\alpha$ -particle from the centre of the nucleus.	1/2	
	<b>Distance of closest approach</b> : It is the minimum distance of the approaching $\alpha$ -particle and the target gold nucleus	1/2	
	$d = \frac{2Ze^2}{4\pi\varepsilon_0 K}$ ; Where K is the kinetic energy		
	<b>Alternatively</b> : Distance of closest approach is the distance of the alpha particle from the centre of gold nucleus where its whole kinetic energy is converted into potential energy		
	ii. $\theta = 0^{\circ}$ ; $b = \text{maximum / almost of atomic size}$	1/2	
	$\theta = 180^{\circ}$ ; $b = \text{minimum} = \text{zero}$	1/2	
	(Note: Allot 1/2 Mark for only formula.)		
	OR		
2.	<b>b</b> )		
	Expressions for kinetic energy ½ + ½		
	Expression for threshold Frequency 1		
	$K = hv_1 - \phi_0$ and $2K = hv_2 - \phi_0$ => $2(hv_1 - \phi_0) = hv_2 - \phi_0$	1/2+1/2	

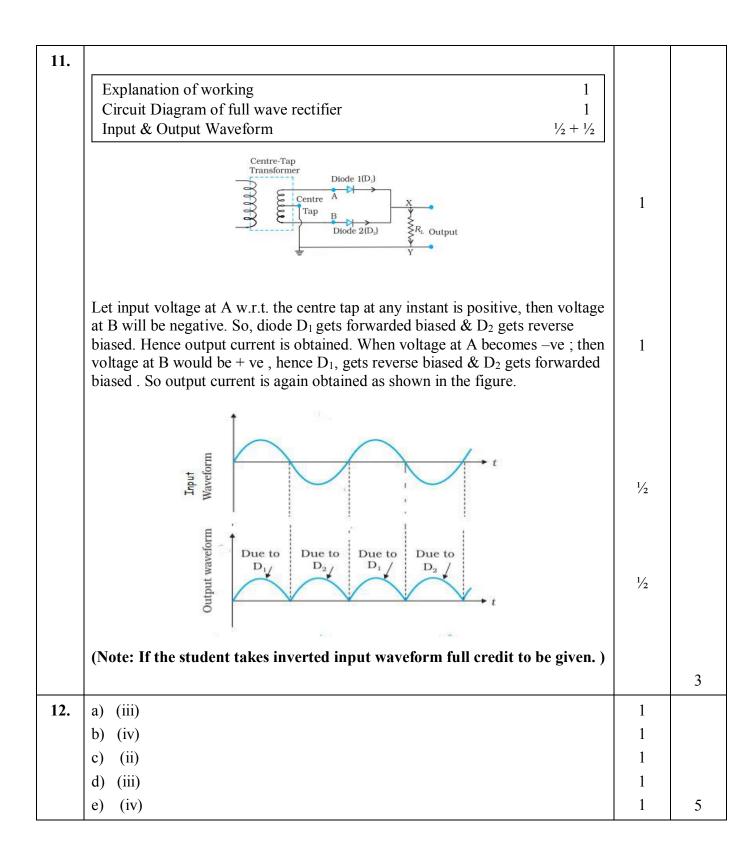
$= h(2\nu_1 - \nu_2) = \phi_0 = h\nu_0$ $= > (2\nu_1 - \nu_2) = \phi_0 = \nu_0$ $= > \nu_0 = 2\nu_1 - \nu_2$ $3.$ Processes Generation of e.m.f.  The three basic processes for generation of e.m.f. by a solar cell are:  (i) Generation of e-h pairs due to light (with $h\nu > E_a$ ) close to the junction.  (ii) Separation of e s and holes due to electric field of the depletion region.  (iii) Collection: e reaching the n-side are collected by the front contact & holes reaching p-side are collected by back contact. Thus, p-side becomes positive and n-side becomes negative giving rise to photo voltage.  SECTION—B  a)  (i) Depiction of plane EM wave $\frac{V_2}{E_2}$ Expression for electric field $\frac{V_2}{V_2}$ Expression for magnetic field $\frac{V_2}{V_2}$ (ii) Characteristics of EM waves $\frac{V_2}{V_2} + \frac{V_2}{V_2} + \frac{V_2}{V_2}$ (i)  (ii) The three characteristics are:  a) They travel with velocity of light.  b) They carry energy and momentum. e) They are transverse in nature.  ((Or any other characteristic given)		$=>2hv_1-2\phi_0=hv_2-\phi_0$	1/2	
$=>(2\nu_1-\nu_2)=\phi_0=\nu_0=\nu_0$ $=>\nu_0=2\nu_1-\nu_2$ 2  3.  Processes Generation of e.m.f. The three basic processes for generation of e.m.f. by a solar cell are: (i) Generation of e-h pairs due to light (with $h\nu > E_e$ ) close to the junction. (ii) Separation of e-s and holes due to electric field of the depletion region. (iii) Collection: e reaching the n-side are collected by the front contact & holes reaching p-side are collected by back contact. Thus, p-side becomes positive and n-side becomes negative giving rise to photo voltage.  SECTION—B  a)  (i) Depiction of plane EM wave Expression for electric field Expression for magnetic field (ii) Characteristics of EM waves $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ (ii) The three characteristics are: a) They travel with velocity of light. b) They carry energy and momentum. c) They are transverse in nature.				
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c) I ney are transverse in nature.		b)They carry energy and momentum.		
(Or any other characteristic given)				
		(Or any other characteristic given)	, 2	

4.	OR		
	b)		
	Naming of EM waves $\frac{1}{2} + \frac{1}{2} + \frac{1}{2}$		
	Uses of EM waves $\frac{1}{2} + \frac{1}{2} + \frac{1}{2}$		
(a) Gamma Rays - Used for cancer treatment		$\frac{1}{2} + \frac{1}{2}$	
	(b) Ultraviolet/Visible/Infrared (either) – Use of anyone of these three.	$\frac{1}{2} + \frac{1}{2}$	
	(c) Infrared Rays – Used in night vision camera, bolometer & thermopiles	$\frac{1}{2} + \frac{1}{2}$	
	(Note: Give full credit to any other use written.)		3
5.			
	(a) Conditions of TIR  (b) Graph  (c) Significance of slope  1		
	<ul> <li>(a) The conditions for total internal reflection to take place are: <ol> <li>The light should travel from denser to rarer medium.</li> <li>The angle of incidence should be greater than the critical angle for a given pair of media.</li> </ol> </li> <li>(b) (i)</li> </ul>	1/ <sub>2</sub> 1/ <sub>2</sub>	
	Apparent depth  Real depth	1	
	(ii)The slope will give $1/\mu$ where $\mu$ is refractive index as per the graph above.	1	3
6.	a) Labelled Ray Diagram of refracting telescope for normal arrangement 1½		
	Derivation of Expression of magnifying power 1½		
	Objective $\int_{\overline{O}}$ Eyepiece $\int_{\overline{C}}$ A	1½	

$m = \frac{\tan \beta}{\tan \alpha} \approx \frac{\beta}{\alpha}$ (as $\alpha, \beta$ are small angles)	1/2	
$\approx \frac{h}{f_e} x \frac{f_0}{h}$	1/2	
$=rac{f_0}{f_e}$	1/2	
$f_e$ (Note: ½ mark to be deducted if arrows not shown or labelling is not done) 6.		
OR OR		
<b>b</b> )		
(i) Intensity distribution curve for diffraction $1\frac{1}{2}$		
(ii) Expression of first maximum from the central maximum $1\frac{1}{2}$		
(i) Intensity distribution curve		
Intensity $ \frac{-3\lambda}{d} \frac{-2\lambda}{d} \frac{-\lambda}{d} = 0  \frac{\lambda}{d} \frac{2\lambda}{d} \frac{3\lambda}{d} $ Diffraction angle $(\theta)$	1½	
For maximum	1/2	
$a\sin\theta = (n + \frac{1}{2})\lambda$		
For first Maximum; $n = 1$	1/2	
For small $\theta$ ; $a\theta = \frac{3\lambda}{2} \implies \theta = \frac{3\lambda}{2a}$		
$\therefore \frac{x}{D} = \frac{3}{2} \frac{\lambda}{a}$	1/2	
$\therefore x = \frac{3}{2} \frac{\lambda D}{a}$		3

7.	Finding the focal length				
	(a) In Air	1½			
	(b) In Liquid	1½			
	(a)				
	$\frac{1}{f_a} = (a \mu^g - 1) \left( \frac{1}{R_1} - \frac{1}{R_2} \right)$			1/2	
	$R_1 = 10 \text{ cm & } R_2 = -20 \text{ cm},  _a \mu^g = 1.5$			1/2	
	$\frac{1}{f_a} = (1.5-1) \left( \frac{1}{10} - \frac{1}{-20} \right)$				
	$f_a = \frac{40}{3} = 13.3 \text{ cm}$			1/2	
	b) $\frac{1}{f_l} = ({}_l \mu^g - 1) \left( \frac{1}{R_1} - \frac{1}{R_2} \right)$			1/2	
	$= \left(\frac{1.5}{1.25} - 1\right) \left(\frac{1}{10} - \frac{1}{-20}\right)$			1/2	
	$f_l = \frac{100}{3} = 33.3 \text{ cm}$			1/2	3
8.	Finding the  a) Radius of orbit  b) Angular Momentum  c) Kinetic & Potential Energy	-	1 1 1		
	a) $r = n^2 r_0 = (2)^2 \times 0.53 = 2.12 \text{ Å}$ b) $L = \frac{nh}{2\pi} = \frac{2 \times 6.63 \times 10^{-34}}{2 \times 3.14} = 2 \times 10^{-34} \text{ kg m/s}$ c) K.E = + 3.4 eV & P.E = -6.8eV			1 1 1	3
9.					<i>J</i>
	(a) Graph (b) Mass Difference Conclusion	1½ 1 ½			
		1/2			

		,		i
	(a)  Note that the control of the co	1½		
	(b)Mass Difference = $55.93494 - 2 \times 27.98191$	1		
	$= -0.02442 \mathrm{u}$			
	Fission not possible.	1/2		
10.			3	
100	Finding the ratio when			
	a) Speed is same			
	b) K.E. is same			
	c) Potential difference is same			
	(a) $\lambda = \frac{h}{p}$	1/2		
	$\frac{\lambda_{\alpha}}{\lambda_{p}} = \frac{h}{m_{\alpha}v_{\alpha}} \times \frac{m_{p}v_{p}}{h} = \frac{1}{4}$	1/2		
	(b)			
	$p = \sqrt{2m(K.E)}$	1/2		
	$\frac{\lambda_{\alpha}}{\lambda_{p}} = \frac{h}{\sqrt{2m_{\alpha}(K.E.)_{\alpha}}} \times \frac{\sqrt{2m_{p}(K.E.)_{p}}}{h} = \sqrt{\frac{m_{p}}{m_{\alpha}}} = \frac{1}{2}$	1/2		
	$(c)$ $v = \sqrt{\frac{2qV}{m}}$	1/2		
	$\frac{\lambda_{\alpha}}{\lambda_{p}} = \frac{h}{m_{\alpha}v_{\alpha}} \times \frac{m_{p}v_{p}}{h} = \frac{m_{p}}{m_{\alpha}} \sqrt{\frac{2q_{p}V}{m_{p}}} \times \sqrt{\frac{m_{\alpha}}{2q_{\alpha}V}}$			
	$= \frac{m_p}{m_\alpha} \times \sqrt{\frac{m_\alpha}{m_p}} \times \sqrt{\frac{q_p}{q_\alpha}} = \frac{1}{2\sqrt{2}}$	1/2	3	
			,	l



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